PUB4753 (PU7457)

Silicon N-Channel Power F-MOS FET (with built-in zener diode)

■ Features

- High avalanche energy capacity
- High electrostatic breakdown voltage
- No secondary breakdown
- High breakdown voltage, large allowable power dissipation
- Allowing Low-voltage drive

Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

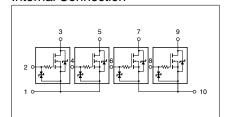
■ Absolute Maximum Ratings (T_C = 25°C)

Parameter		Symbol	Ratings	Unit	
Drain to Source breakdown voltage		V _{DSS}	100 ± 15	V	
Gate to Source voltage		V _{GSS}	±20	V	
Drain current	DC	I_{D}	±3	A	
	Pulse	I_{DP}	±9	A	
Avalanche energy capacity	Non repetition	EAS*	22.5	mJ	
Allowable power	$T_C = 25^{\circ}C$	D	15	W	
dissipation	Ta = 25°C	$P_{\rm D}$	3.5		
Channel temperature		T _{ch}	150	°C	
Storage temperature		T _{stg}	-55 to +150	°C	

^{*} L = 5mH, $I_L = 3A$, 1 pulse

Unit: mm 25.3±0.2 40±0.2 0.8±0.25 0.5±0.15 0.5±0.15 0.5±0.15 0.5±0.15 0.5±0.15 G: Gate D: Drain S: Source 10-Lead Plastic SIL Package

Internal Connection

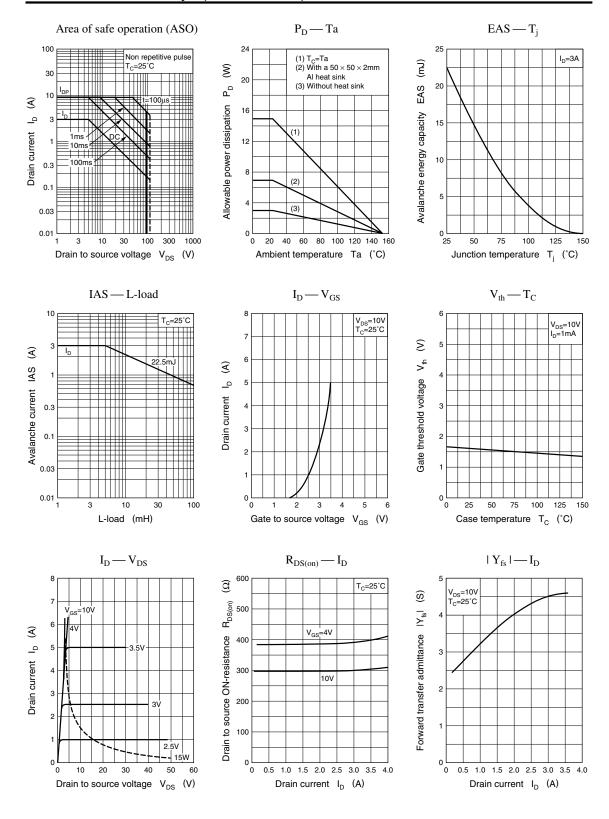


■ Electrical Characteristics ($T_C = 25$ °C)

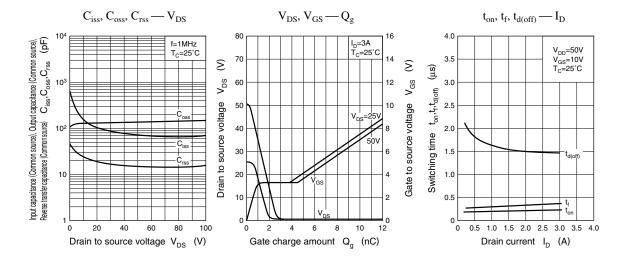
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	I_{DSS}	$V_{DS} = 80V, V_{GS} = 0$			10	μA
Gate to Source leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0$			±10	μA
Drain to Source breakdown voltage	$V_{\rm DSS}$	$I_D = 1 \text{mA}, V_{GS} = 0$	85		115	V
Gate threshold voltage	V_{th}	$V_{DS} = 10V, I_D = 1mA$	1		2.5	V
Drain to Source ON-resistance	R _{DS(on)1}	$V_{GS} = 10V, I_D = 2A$		300	450	mΩ
	R _{DS(on)2}	$V_{GS} = 4V, I_D = 2A$		400	600	mΩ
Forward transfer admittance	Y _{fs}	$V_{DS} = 10V, I_{D} = 2A$	2.5	4		S
Diode forward voltage	V _{DSF}	$I_{DR} = 3A, V_{GS} = 0$			-1.6	V
Input capacitance (Common Source)	C _{iss}	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$		130		pF
Output capacitance (Common Source)	Coss			160		pF
Reverse transfer capacitance (Common Source)	C _{rss}			25		pF
Turn-on time	t _{on}	$V_{GS} = 10V, I_D = 2A$ $V_{DD} = 50V, R_L = 25\Omega$		0.2		μs
Fall time	t_{f}			0.3		μs
Turn-off time (delay time)	t _{d(off)}			1.5		μs

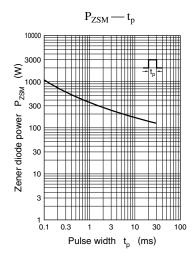
Note) The part number in the parenthesis shows conventional part number.

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